



AC Input 4-Pin Mini-Flat Phototransistor Optocoupler

Features

- High isolation 3750 VRMS
- CTR flexibility available see order information
- AC input with transistor output
- Temperature range - 55 °C to 110 °C
- Regulatory Approvals
 - UL - UL1577 (E364000)
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC – GB4943.1, GB8898
 - IEC60065, IEC60950

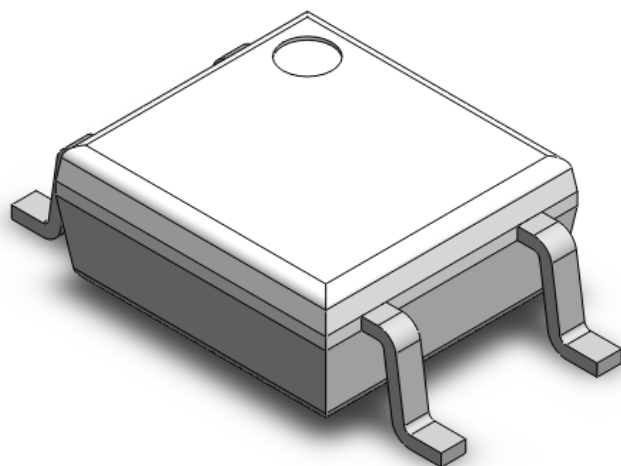
Description

These series of AC input optocoupler consists of a photo transistor optically coupled to two gallium arsenide Infrared-emitting diodes in a 4-lead Mini-Flat package.

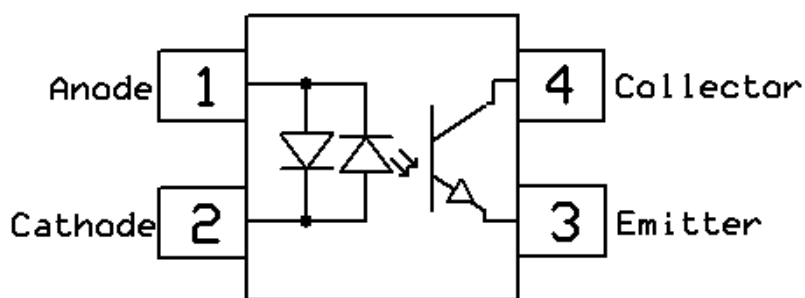
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline



Schematic



**AC Input 4-Pin Mini-Flat Phototransistor Optocoupler****Absolute Maximum Rating at 25°C**

Symbol	Parameters	Ratings	Units	Notes
V _{ISO}	Isolation voltage	3750	V _{RMS}	
T _{OPR}	Operating temperature	-55 ~ +110	°C	
T _{STG}	Storage temperature	-55 ~ +150	°C	
T _{SOL}	Soldering temperature	260	°C	
P _{TOT}	Total power dissipation	200	mW	
Emitter				
I _F	Forward current	±50	mA	
I _{F(TRANS)}	Peak transient current (≤1μs P.W,300pps)	1	A	
P _D	Power dissipation	70	mW	
Detector				
P _C	Power dissipation	150	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	80	V	
B _{VECO}	Emitter-Collector Breakdown Voltage	7	V	
I _C	Collector Current	50	mA	



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Electrical Characteristics $T_A = 25^\circ\text{C}$ (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V_F	Forward voltage	$I_F=10\text{mA}$		1.24	1.4	V	
C_{IN}	Input Capacitance	$f=1\text{kHz}$	-	45	-	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$B_{V_{CEO}}$	Collector-Emitter Breakdown	$I_C=100\mu\text{A}$	80	-	-	V	
$B_{V_{ECO}}$	Emitter-Collector Breakdown	$I_E=100\mu\text{A}$	7	-	-	V	
I_{CEO}	Collector-Emitter Dark Current	$V_{CE}=20\text{V}, I_F=0\text{mA}$	-	-	100	nA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	$I_F=\pm 1\text{mA}, V_{CE}=5\text{V}$	20	-	300	%	
			50	-	150		
	CTR Symmetry	$I_F=\pm 1\text{mA}, V_{CE}=5\text{V}$	0.7	-	1.3		
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage	$I_F=\pm 20\text{mA}, I_C=1\text{mA}$	-	0.1	0.2	V	
R_{IO}	Isolation Resistance	$V_{IO}=500\text{V}_{DC}$	5×10^{10}	-	-		
C_{IO}	Isolation Capacitance	$f=1\text{MHz}$	-	0.6	1.0	pF	

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
t_r	Rise Time	$I_C=2\text{mA}, V_{CE}=2\text{V}, R_L=100$	-	6	18	μs	
t_f	Fall Time		-	8	18		



Typical Characteristic Curves

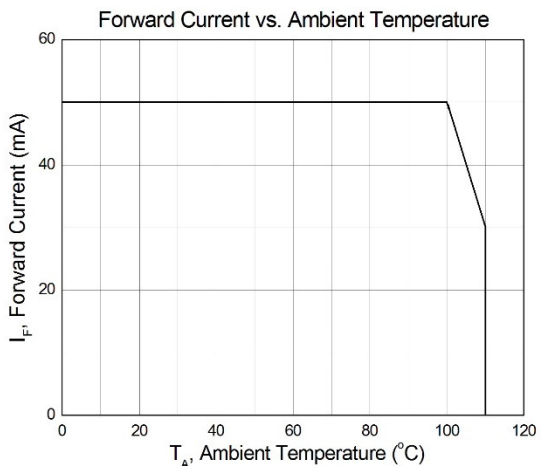


Figure 1

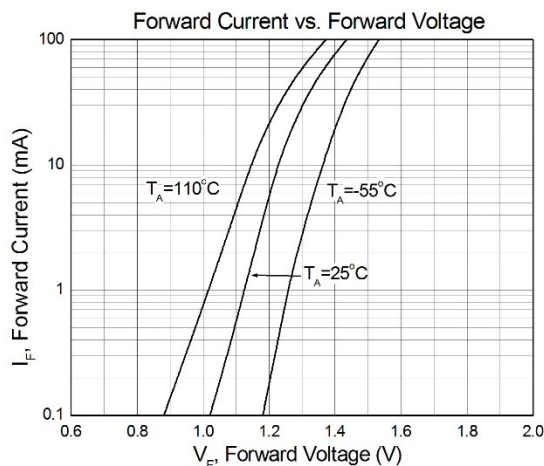


Figure 2

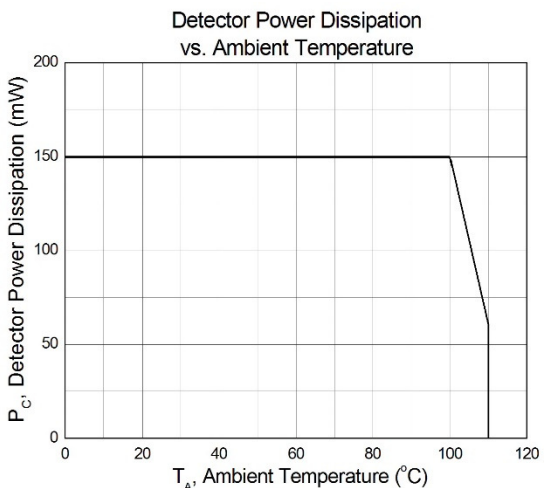


Figure 3

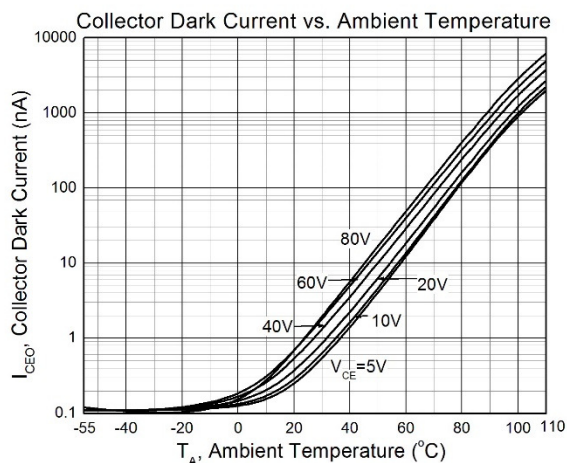


Figure 4

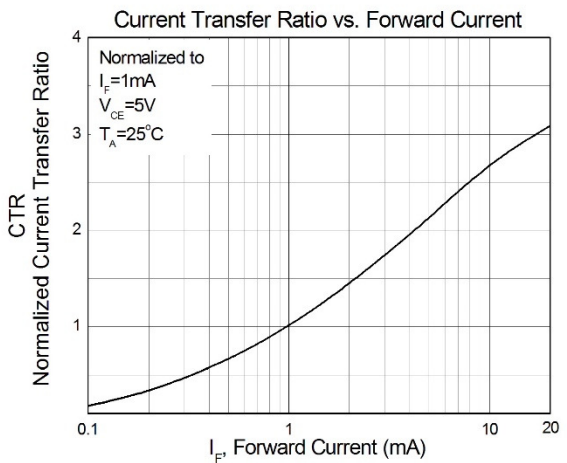


Figure 5

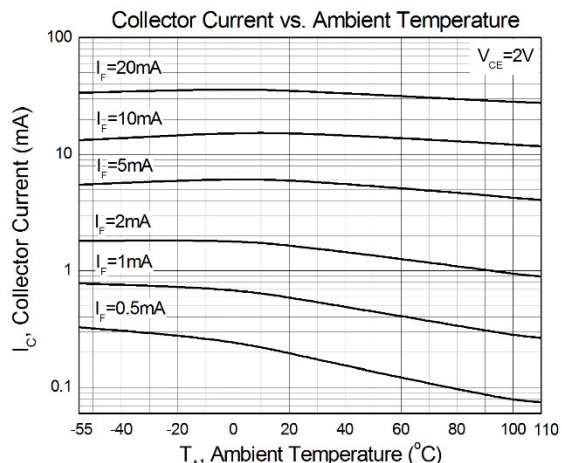


Figure 6



AC Input 4-Pin Mini-Flat Phototransistor Optocoupler

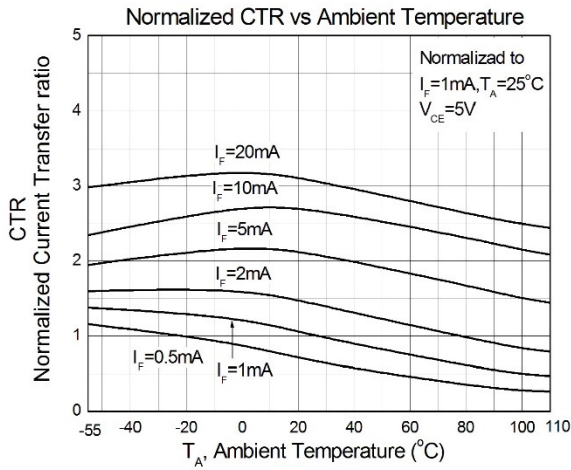


Figure 7

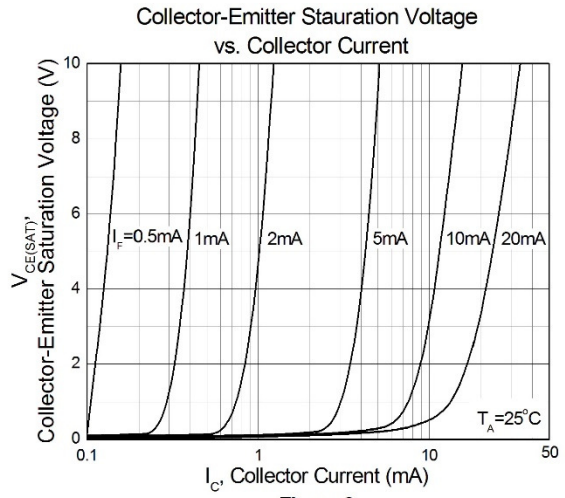


Figure 8

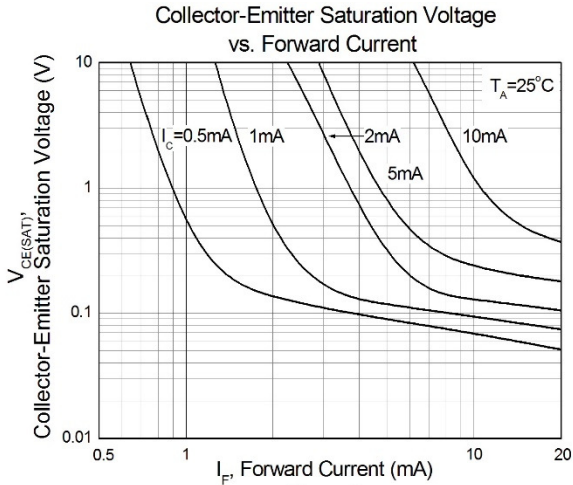


Figure 9

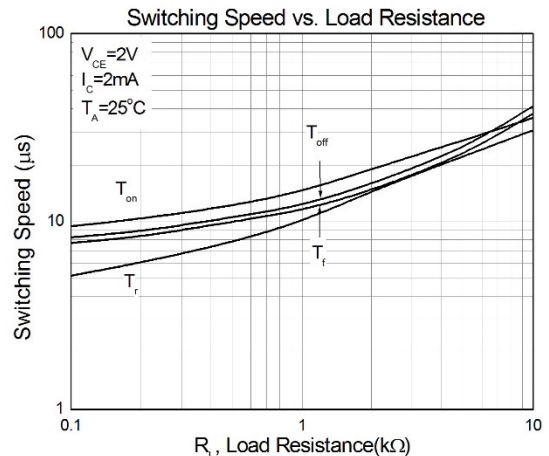


Figure 10

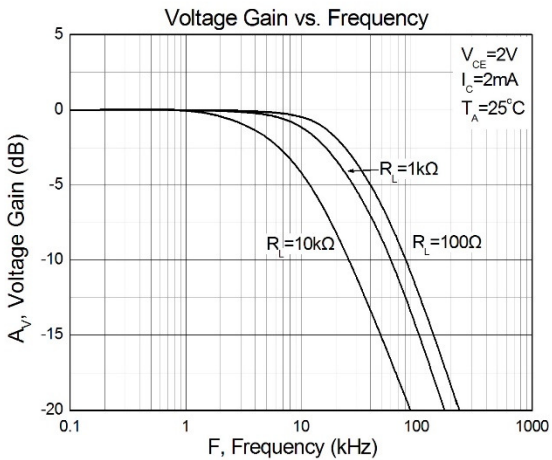


Figure 11

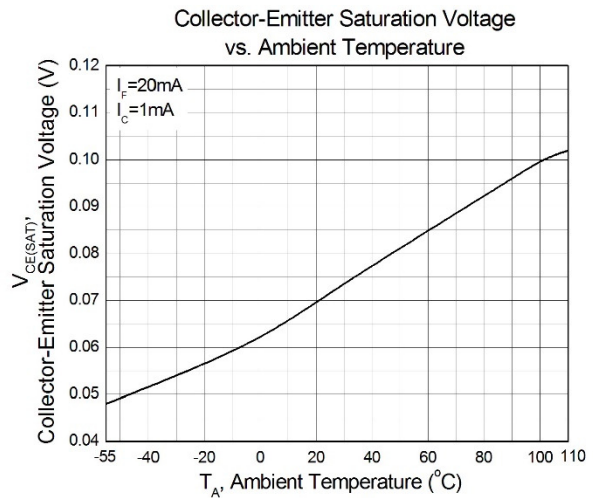
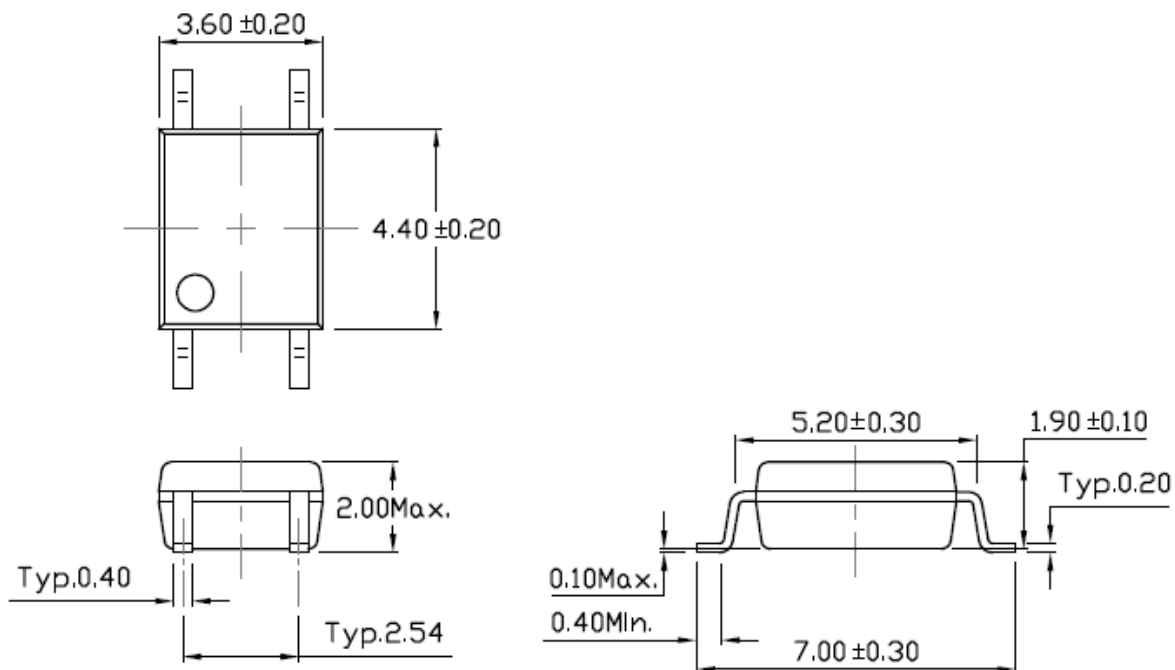


Figure 12

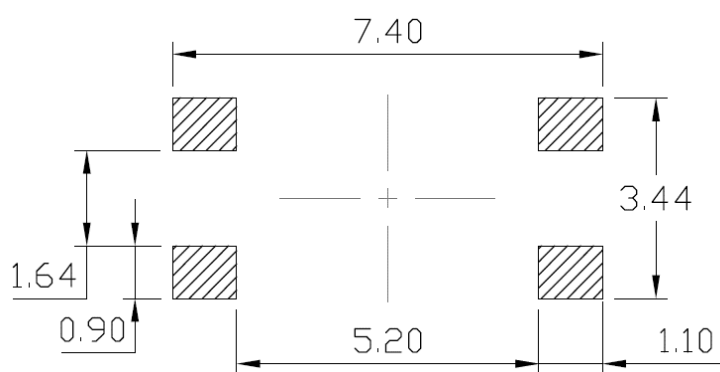


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Package Dimension *Dimensions in mm unless otherwise stated*

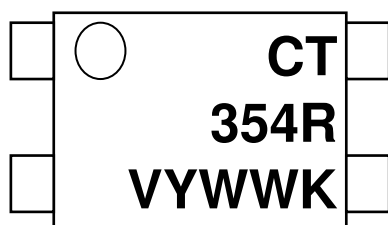


Recommended Solder Mask *Dimensions in mm unless otherwise stated*





Marking Information

**Note:**

CT : Denotes "CT Micro"
354 : Product Number
R : CTR Rank
V : VDE Option
Y : Fiscal Year
WW : Work Week
K : Manufacturing Code

Ordering Information

CT354X(V)(Z)

X = Part No. (X=A or None)

V = VDE option (V or None)

Z = Tape and reel option (T1 or T2)

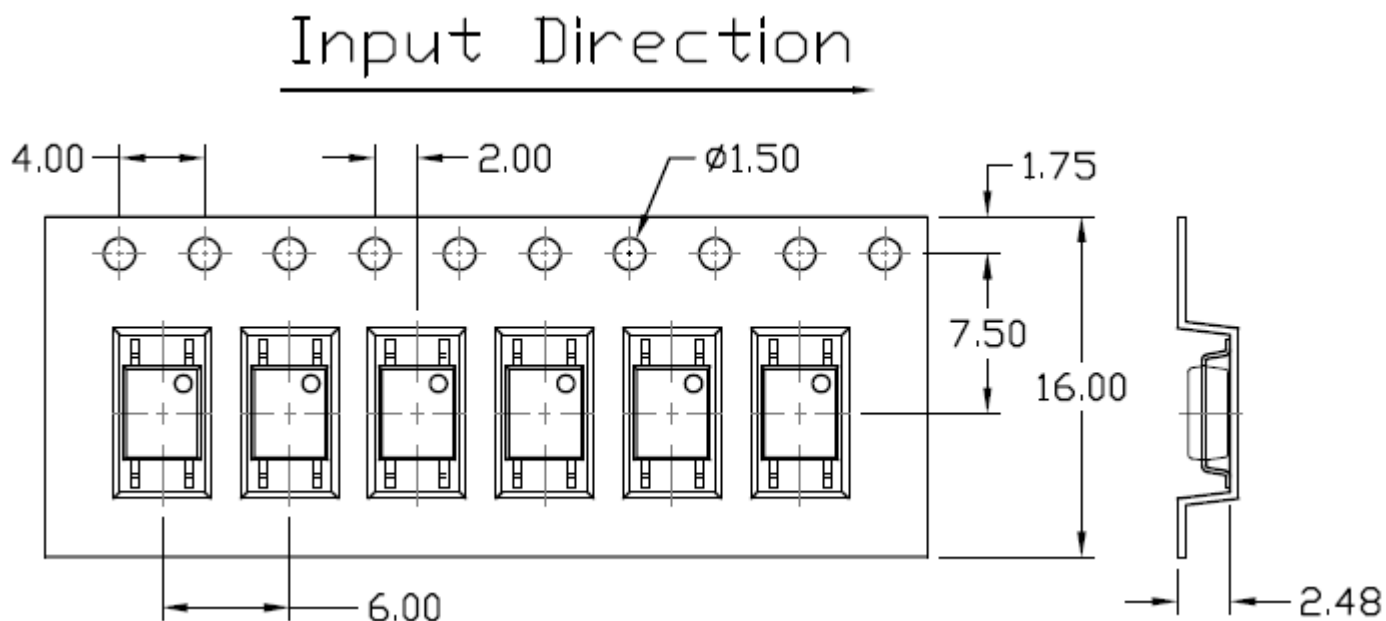
Option	Description	Quantity
T1	Surface Mount Lead Forming – With Option 1 Taping	3000 Units/Reel
T2	Surface Mount Lead Forming – With Option 2 Taping	3000 Units/Reel



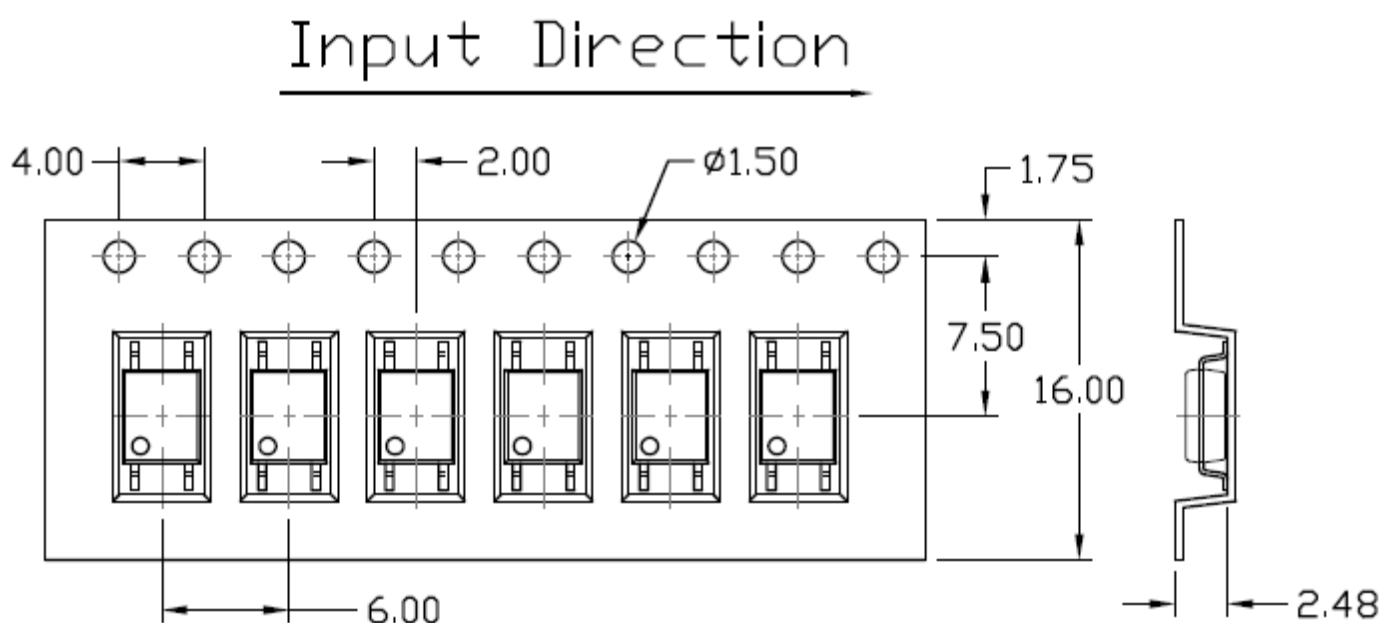
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Carrier Tape Specifications *Dimensions in mm unless otherwise stated*

Option (T1)



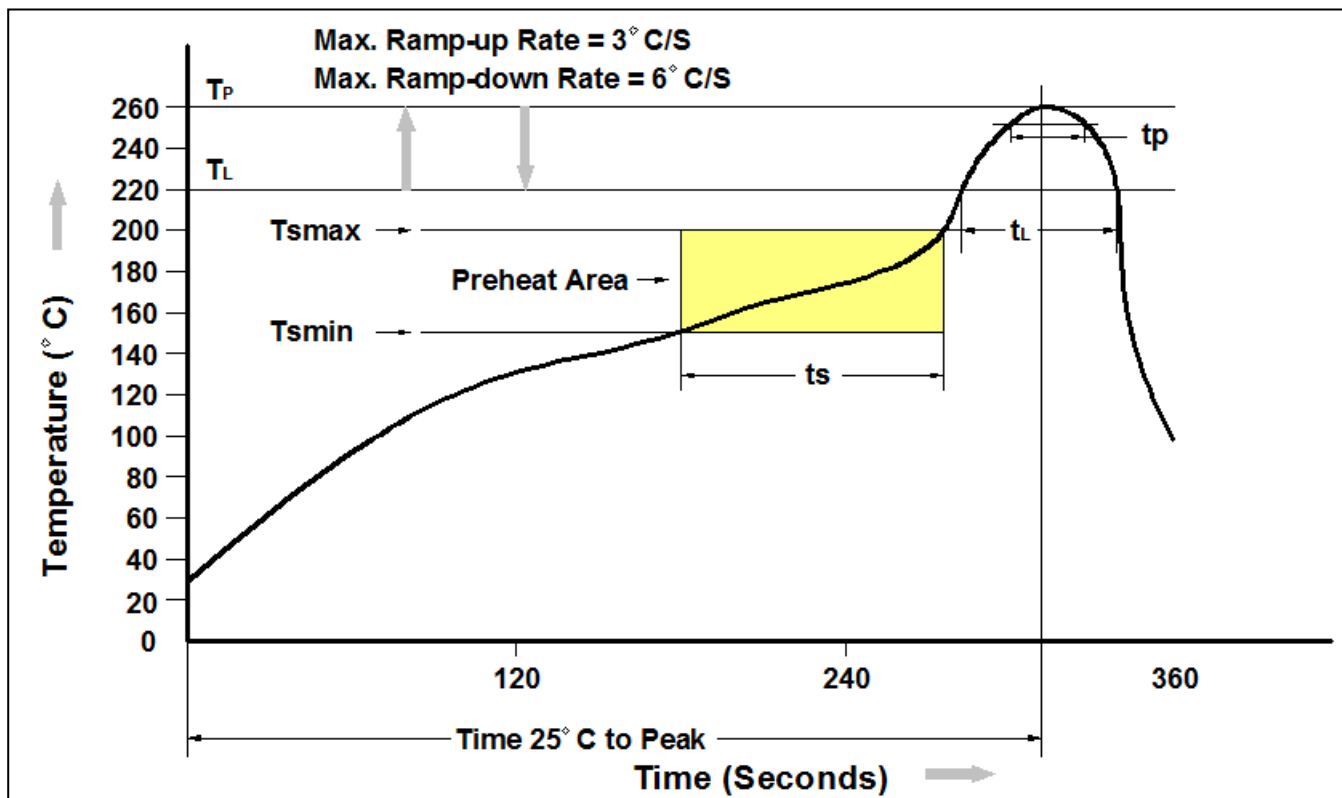
Option (T1)





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Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	150 °C
Temperature Max. (T_{smax})	200 °C
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds
Ramp-up Rate (t_L to t_P)	3°C/second max.
Liquidous Temperature (T_L)	217 °C
Time (t_L) Maintained Above (T_L)	60 – 150 seconds
Peak Body Package Temperature	260 °C +0 °C / -5 °C
Time (t_P) within 5 °C of 260 °C	30 seconds
Ramp-down Rate (T_P to T_L)	6°C/second max
Time 25 °C to Peak Temperature	8 minutes max.



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